TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSIII)

# 2SK2607

# Chopper Regulator, DC-DC Converter and Moter Drive Applications

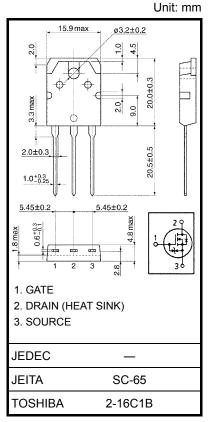
• Low drain-source ON resistance : RDS (ON) = 1.0  $\Omega$  (typ.)

• High forward transfer admittance  $: |Y_{fs}| = 7.0 \text{ S (typ.)}$ • Low leakage current  $: I_{DSS} = 100 \text{ }\mu\text{A (max) (V}_{DS} = 640 \text{ V)}$ 

• Enhancement mode :  $V_{th} = 2.0 \text{ to } 4.0 \text{ V (Vps} = 10 \text{ V, Ip} = 1 \text{ mA)}$ 

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	800	V	
Drain-gate voltage (R <sub>GS</sub> = 20 kΩ)		$V_{DGR}$	800	٧	
Gate-source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC (Note 1)	ID	9	Α	
	Pulse (Note 1)	I <sub>DP</sub>	27	ı	
Drain power dissipation	r (Tc = 25°C)	P <sub>D</sub>	150	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	778	mJ	
Avalanche current		I <sub>AR</sub>	9	Α	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	15	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	0.883	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 17.4 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 9 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

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## **Electrical Characteristics (Ta = 25°C)**

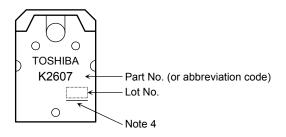
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I <sub>G</sub> = ±10 μA, V <sub>DS</sub> = 0 V	±30	_	_	V
Drain cut-off cui	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = 640 V, V <sub>GS</sub> = 0 V	_	_	100	μA
Drain-source br	eakdown voltage	V <sub>(BR) DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	800	_	_	V
Gate threshold v	oltage/	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	_	4.0	V
Drain-source Ol	N resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4 A,	_	1.0	1.2	Ω
Forward transfer	r admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 4 A	3.0	7.0	_	S
Input capacitano	e	C <sub>iss</sub>		_	2160	_	
Reverse transfer	r capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	45	_	pF
Output capacitance		Coss	]	_	200	_	
Switching time	Rise time	t <sub>r</sub>	$V_{GS} \stackrel{10 \text{ V}}{\text{O} \text{ V}} \stackrel{I_{D} = 4 \text{ A}}{\text{N}} \stackrel{\text{O} \text{ V}_{out}}{\text{N}} \stackrel{\text{RL} = 100 \Omega}{\text{N}} \stackrel{\text{RL} = 400 \text{ V}}{\text{N}} \stackrel{\text{RL} = 400 \text{ V}}{\text$	_	25	_	
	Turn-on time	t <sub>on</sub>		_	60	_	ns
	Fall time	t <sub>f</sub>		_	25	_	113
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, $t_{\rm w} = 10  \mu \rm s$	ı	110		
Total gate charge (gate-source plus gate-drain)		Qg		_	68	_	
Gate-source charge		$Q_{gs}$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 9 \text{ A}$		38	_	nC
Gate-drain ("miller") Charge		$Q_{gd}$		_	30	_	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	9	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	27	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 9 A, V <sub>GS</sub> = 0 V	_	_	-1.9	V
Reverse recovery time	t <sub>rr</sub>	I <sub>DR</sub> = 9 A, V <sub>GS</sub> = 0 V, dI <sub>DR</sub> / dt = 100 A / µs	1	1000	1	ns
Reverse recovery charge	Q <sub>rr</sub>	1DR - 9 A, VGS - 0 V, αDR / αt - 100 A / μs	_	12	_	μC

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### Marking

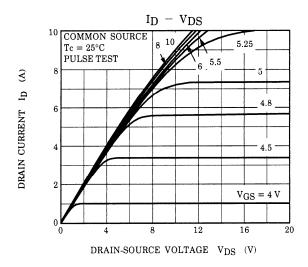


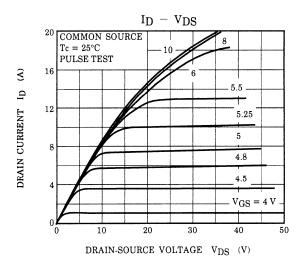
Note 4: A line under a Lot No. identifies the indication of product Labels.

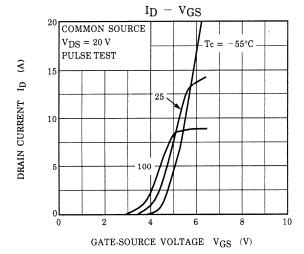
Not underlined: [[Pb]]/INCLUDES > MCV

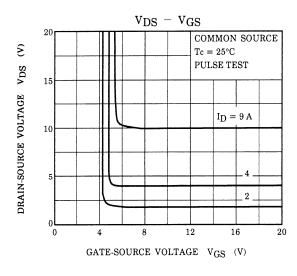
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

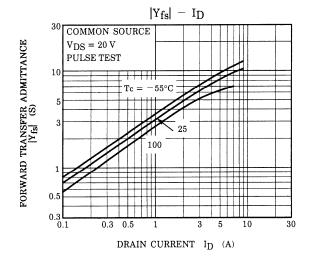
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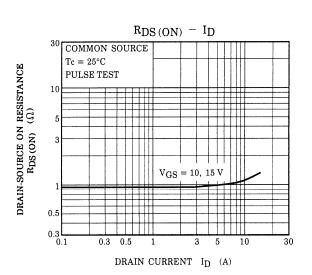


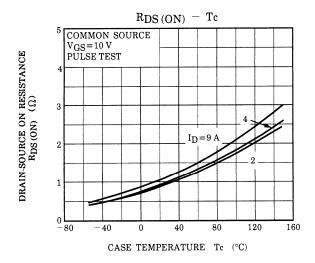


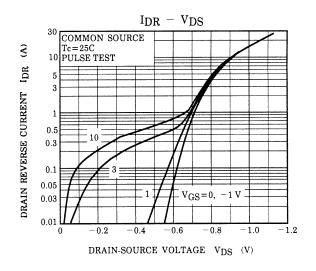


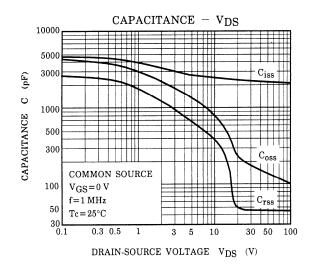


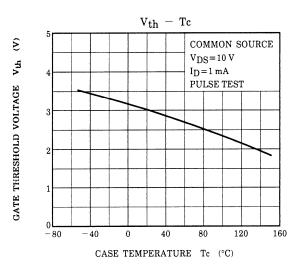


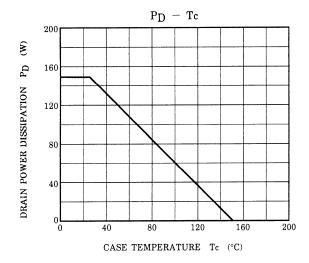


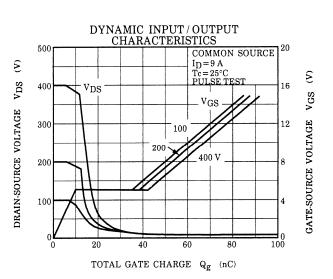




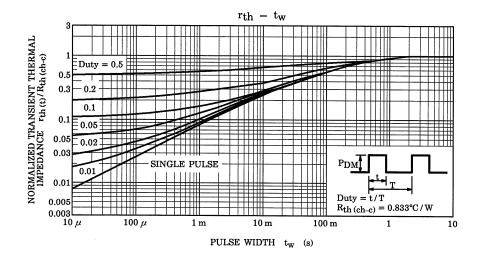


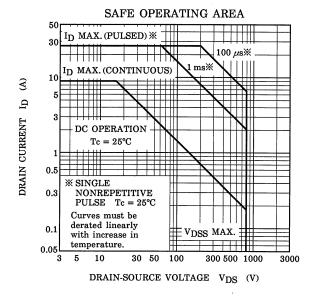


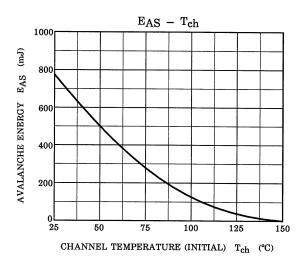


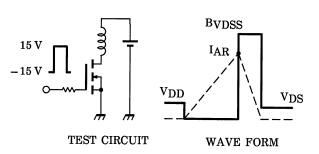


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$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 90~V,~L = 17.4~mH \end{aligned} \quad E_{AS} &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - VDD} \right) \end{aligned}$$

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